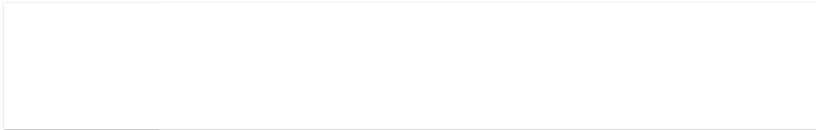


Thyristor

$$V_{RRM} = 1600 \text{ V}$$

$$I_{TAV} = 30 \text{ A}$$

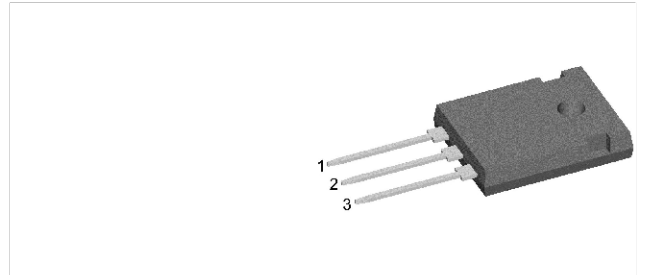
$$V_T = 1.3 \text{ V}$$



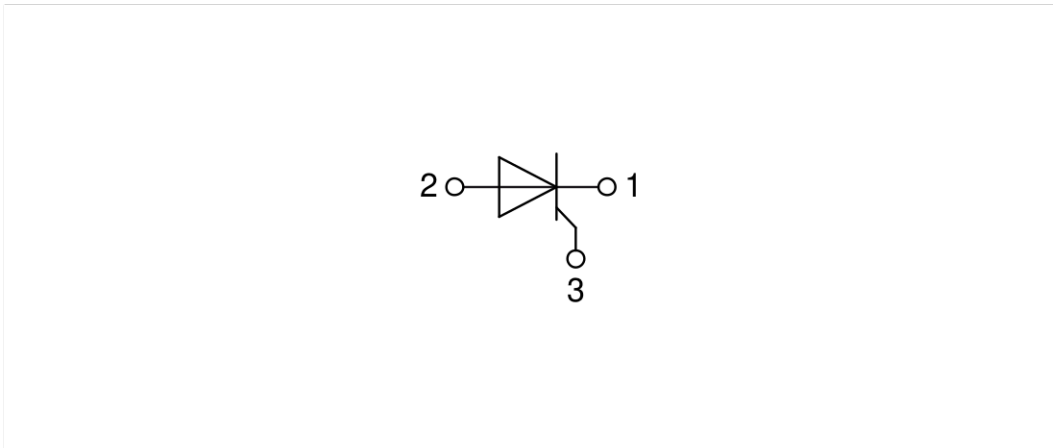
Single Thyristor

Part number

CS30-16io1



Backside: anode



Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability

Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

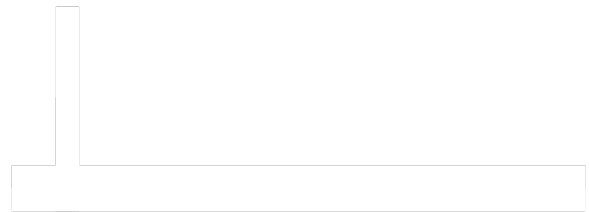
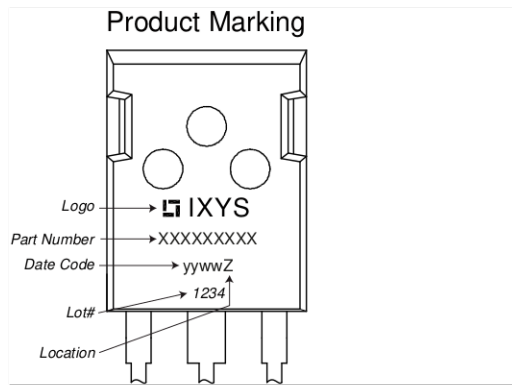
Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.



Thyristor				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
$V_{RSM/DSM}$	max. non-repetitive reverse/forward blocking voltage				1700	V	
$V_{RRM/DRM}$	max. repetitive reverse/forward blocking voltage				1600	V	
I_{RD}	reverse current, drain current	$V_{RD} = 1600$ V			50	μ A	
		$V_{RD} = 1600$ V			2	mA	
V_T	forward voltage drop	$I_T = 30$ A			1.30	V	
		$I_T = 60$ A			1.63	V	
		$I_T = 30$ A	$T_{VJ} = 125^\circ$ C			1.30	V
		$I_T = 60$ A	$T_{VJ} = 125^\circ$ C			1.71	V
I_{TAV}	average forward current	$T_C = 120^\circ$ C			30	A	
$I_{T(RMS)}$	RMS forward current	180° sine			47	A	
V_{T0}	threshold voltage	} for power loss calculation only			0.87	V	
r_T	slope resistance				14.2	m Ω	
R_{thJC}	thermal resistance junction to case				0.5	K/W	
R_{thCH}	thermal resistance case to heatsink			0.3		K/W	
P_{tot}	total power dissipation		$T_C = 25^\circ$ C		250	W	
I_{TSM}	max. forward surge current	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^\circ$ C		400	A	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0$ V		430	A	
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 150^\circ$ C		340	A	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0$ V		365	A	
I^2t	value for fusing	t = 10 ms; (50 Hz), sine	$T_{VJ} = 45^\circ$ C		800	A ² s	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0$ V		770	A ² s	
		t = 10 ms; (50 Hz), sine	$T_{VJ} = 150^\circ$ C		580	A ² s	
		t = 8,3 ms; (60 Hz), sine	$V_R = 0$ V		555	A ² s	
C_J	junction capacitance	$V_R = 400$ V f = 1 MHz	$T_{VJ} = 25^\circ$ C	16		pF	
P_{GM}	max. gate power dissipation	$t_p = 30$ μ s	$T_C = 150^\circ$ C		10	W	
		$t_p = 300$ μ s			5	W	
P_{GAV}	average gate power dissipation				0.5	W	
$(di/dt)_{cr}$	critical rate of rise of current	$T_{VJ} = 125^\circ$ C; f = 50 Hz repetitive, $I_T = 90$ A			150	A/ μ s	
		$t_p = 200$ μ s; $di_G/dt = 0.3$ A/ μ s; $I_G = 0.3$ A; $V = \frac{2}{3} V_{DRM}$ non-repet., $I_T = 30$ A			500	A/ μ s	
$(dv/dt)_{cr}$	critical rate of rise of voltage	$V = \frac{2}{3} V_{DRM}$ $R_{GK} = \infty$; method 1 (linear voltage rise)	$T_{VJ} = 125^\circ$ C		1000	V/ μ s	
V_{GT}	gate trigger voltage	$V_D = 6$ V	$T_{VJ} = 25^\circ$ C		1	V	
			$T_{VJ} = -40^\circ$ C		1.2	V	
I_{GT}	gate trigger current	$V_D = 6$ V	$T_{VJ} = 25^\circ$ C		55	mA	
			$T_{VJ} = -40^\circ$ C		80	mA	
V_{GD}	gate non-trigger voltage	$V_D = \frac{2}{3} V_{DRM}$	$T_{VJ} = 125^\circ$ C		0.2	V	
I_{GD}	gate non-trigger current				5	mA	
I_L	latching current	$t_p = 10$ μ s	$T_{VJ} = 25^\circ$ C		150	mA	
		$I_G = 0.3$ A; $di_G/dt = 0.3$ A/ μ s					
I_H	holding current	$V_D = 6$ V $R_{GK} = \infty$	$T_{VJ} = 25^\circ$ C		100	mA	
t_{gd}	gate controlled delay time	$V_D = \frac{1}{2} V_{DRM}$ $I_G = 0.3$ A; $di_G/dt = 0.3$ A/ μ s	$T_{VJ} = 25^\circ$ C		2	μ s	
t_q	turn-off time	$V_R = 100$ V; $I_T = 30$ A; $V = \frac{2}{3} V_{DRM}$ $di/dt = 15$ A/ μ s $dv/dt = 20$ V/ μ s $t_p = 200$ μ s	$T_{VJ} = 125^\circ$ C	150		μ s	



Package TO-247			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			70	A
T_{VJ}	virtual junction temperature		-40		150	°C
T_{op}	operation temperature		-40		125	°C
T_{stg}	storage temperature		-40		150	°C
Weight				6		g
M_D	mounting torque		0.8		1.2	Nm
F_C	mounting force with clip		20		120	N



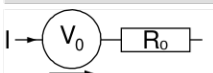
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	CS30-16io1	CS30-16io1	Tube	30	466581

Similar Part	Package	Voltage class
CS30-12io1	TO-247AD (3)	1200
CS30-14io1	TO-247AD (3)	1400

Equivalent Circuits for Simulation

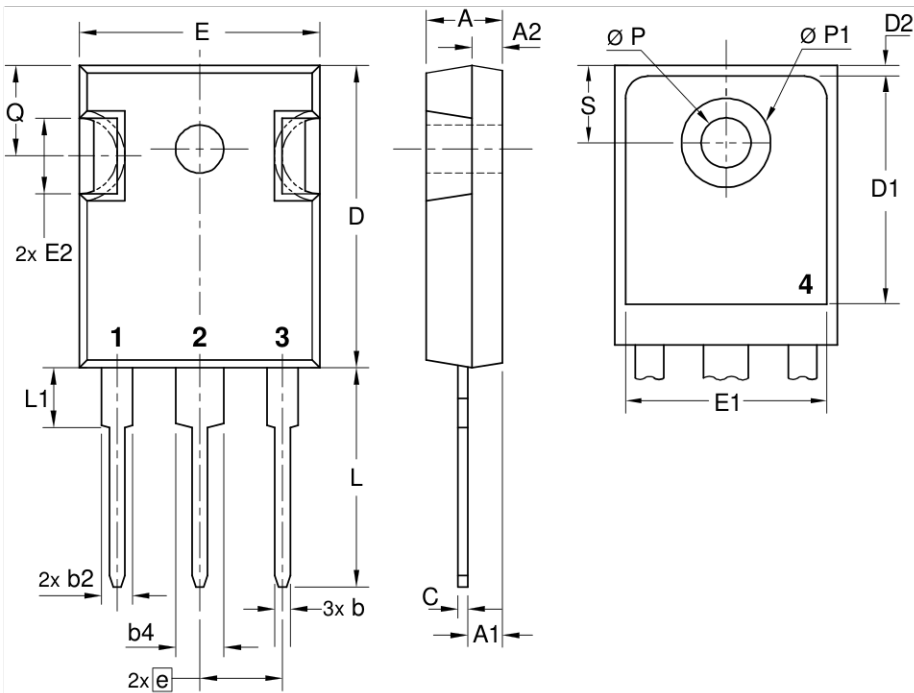
* on die level

$T_{VJ} = 150^{\circ}C$

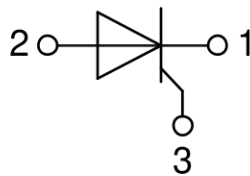


Thyristor

$V_{0\ max}$	threshold voltage	0.87	V
$R_{0\ max}$	slope resistance *	11.7	mΩ

Outlines TO-247


Sym.	Inches		Millimeter	
	min.	max.	min.	max.
A	0.185	0.209	4.70	5.30
A1	0.087	0.102	2.21	2.59
A2	0.059	0.098	1.50	2.49
D	0.819	0.845	20.79	21.45
E	0.610	0.640	15.48	16.24
E2	0.170	0.216	4.31	5.48
e	0.215 BSC		5.46 BSC	
L	0.780	0.800	19.80	20.30
L1	-	0.177	-	4.49
Ø P	0.140	0.144	3.55	3.65
Q	0.212	0.244	5.38	6.19
S	0.242 BSC		6.14 BSC	
b	0.039	0.055	0.99	1.40
b2	0.065	0.094	1.65	2.39
b4	0.102	0.135	2.59	3.43
c	0.015	0.035	0.38	0.89
D1	0.515	-	13.07	-
D2	0.020	0.053	0.51	1.35
E1	0.530	-	13.45	-
Ø P1	-	0.29	-	7.39



Thyristor

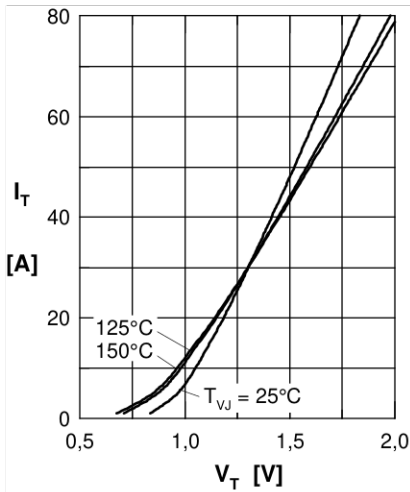


Fig. 1 Forward characteristics

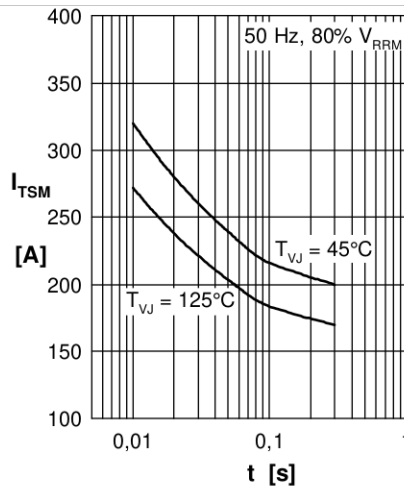


Fig. 2 Surge overload current

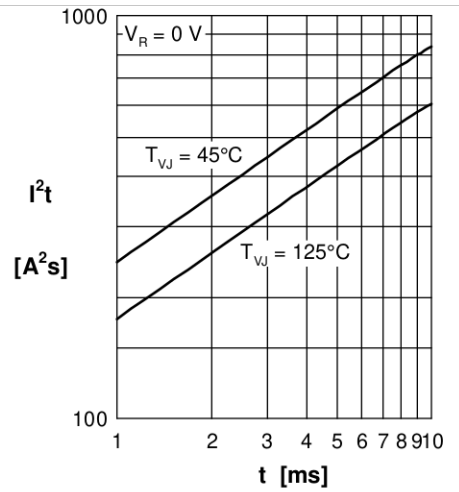


Fig. 3 I^2t versus time (1-10 ms)

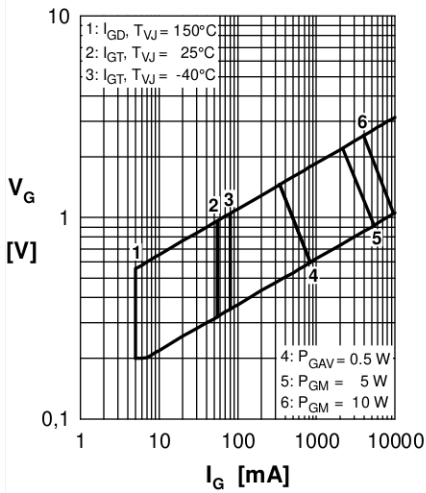


Fig. 4 Gate trigger characteristics

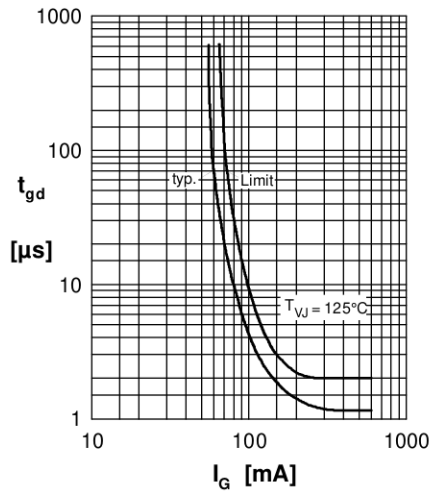


Fig. 5 Gate controlled delay time

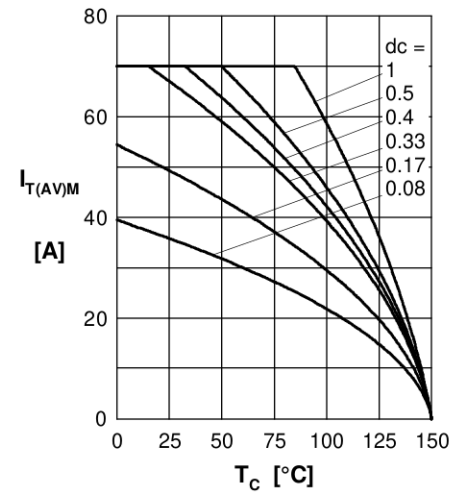


Fig. 6 Max. forward current at case temperature

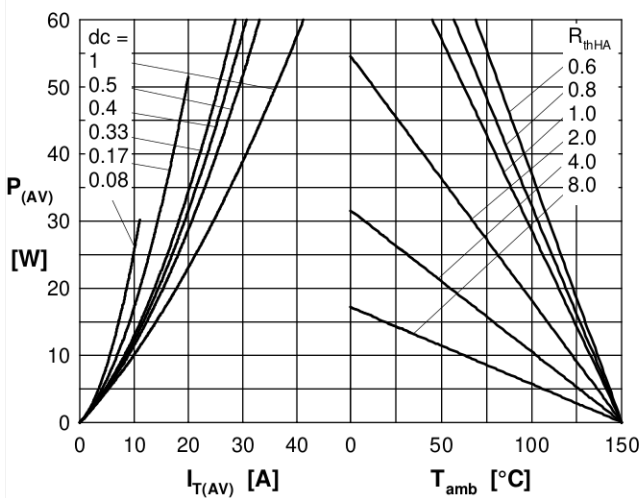


Fig. 7a Power dissipation versus direct output current
Fig. 7b and ambient temperature

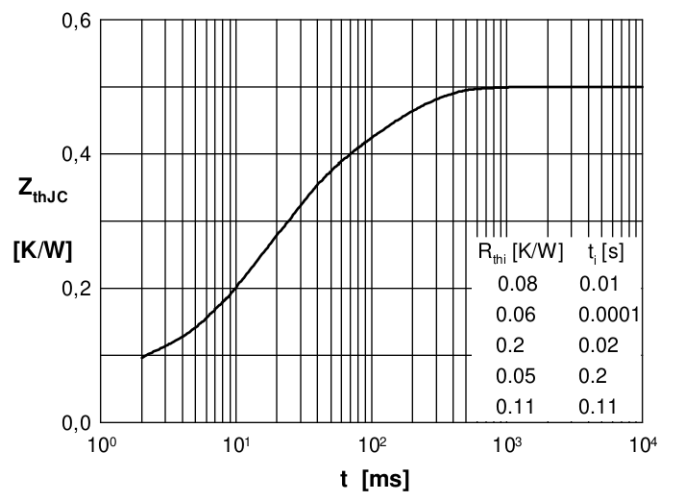


Fig. 8 Transient thermal impedance junction to case

